

## GLP2950

100mA Low-Dropout Voltage Regulator

### Description

The GLP2950 is a monolithic integrated voltage regulator with low dropout voltage, and low quiescent current. It includes many features that suitable for different applications.

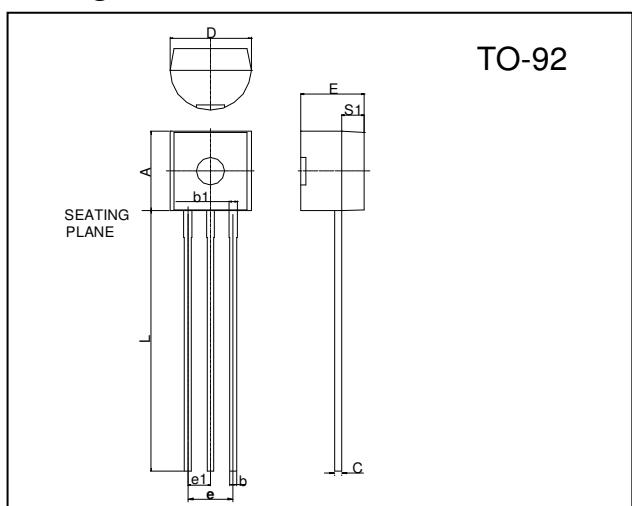
### Features

- High accuracy 2.5, 3.0, 3.3, 3.6 or 5V fixed output
- Extremely low quiescent current and dropout voltage
- Extremely tight load and line regulation
- Current and thermal Limiting
- Very low temperature coefficient

### Applications

- Battery powered equipment
- Cellular Phones

### Package Dimensions

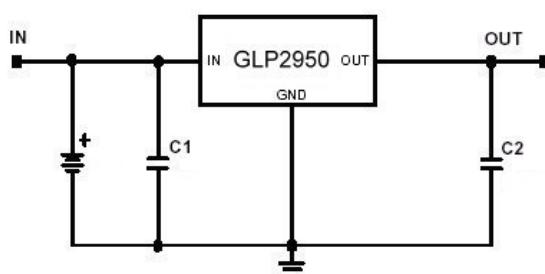


### Marking :

Date Code →	2950	Vout
	□□	2.5V:25
	□□	3.0V:30
	□□	3.3V:33
	□□	3.6V:36
	□□	5.0V:50
1:Vout		
2:Gnd		
3:Vin		
	1	
	2	
	3	

REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	4.45	4.7	D	4.44	4.7
S1	1.02	-	E	3.30	3.81
b	0.36	0.51	L	12.70	-
b1	0.36	0.76	e1	1.150	1.390
C	0.36	0.51	e	2.42	2.66

### Application Circuit



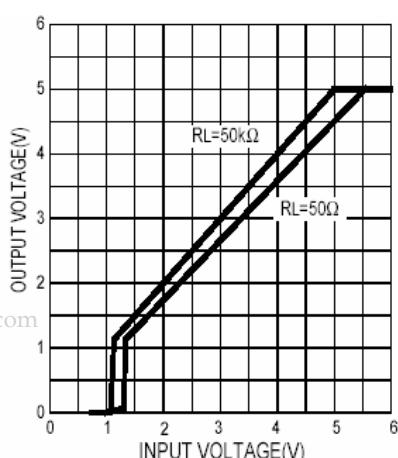
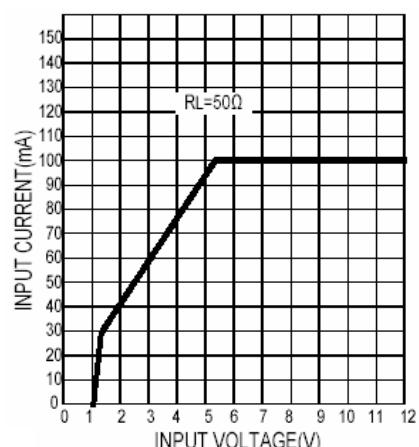
### Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Input Voltage	V <sub>CC</sub>	-0.3 ~ +30	V
Output Current	I <sub>OUT</sub>	100	mA
Output Voltage	V <sub>OUT</sub>	2.5 ~ 5.0	V
Storage Temperature	T <sub>STG</sub>	-65 ~ +150	°C
Maximum Junction Temperature	T <sub>JMAX</sub>	150	°C
Operating Junction Temperature	T <sub>J</sub>	-40 ~ +125	°C

**Electrical Characteristics (T<sub>J</sub>=25°C, V<sub>IN</sub>=6V, I<sub>O</sub>=100μA, and C<sub>O</sub>=1μF, unless otherwise specified)**

Parameter	Symbol	Condition	Min	TYP	Max	Unit
Output Voltage	V <sub>OUT</sub>	GLP2950-25	100μA≤I <sub>O</sub> ≤100mA T <sub>J</sub> ≤T <sub>JMAX</sub>	2.45	2.5	2.55
		GLP2950-30		2.94	3.0	3.06
		GLP2950-33		3.23	3.3	3.36
		GLP2950-36		3.53	3.6	3.67
		GLP2950-50		4.90	5.0	5.10
Line Regulation	REG <sub>LINE</sub>	V <sub>O</sub> +1≤V <sub>IN</sub> ≤30V	-	0.04	0.4	%
Load Regulation	REG <sub>LOAD</sub>	100μA≤I <sub>O</sub> ≤100mA	-	0.1	0.3	%
Current Limit	I <sub>LIM</sub>	V <sub>OUT</sub> =0	-	160	200	mA
Output Voltage Temperature Coefficient	T <sub>C</sub>		-	20		ppm/°C
Dropout Voltage	V <sub>DROPOUT</sub>	I <sub>O</sub> =100μA	-	50	80	mV
		I <sub>O</sub> =100mA (Note1)	-	380	450	
Ground Current	I <sub>Q</sub>	I <sub>O</sub> =100μA	-	75	120	μA
		I <sub>O</sub> =100mA	-	8	12	mA
Dropout Ground Current		V <sub>IN</sub> =V <sub>O</sub> -0.5V, I <sub>O</sub> =100μA	-	110	170	μA
Output Voltage Noise f=10Hz~100kHz	e <sub>N</sub>	C <sub>O</sub> =1μF	-	430	-	μV
		C <sub>O</sub> =200μF	-	160	-	

Note 1: Dropout Voltage is defined as the input to output differential at which the output voltage drops 100mV below its nominal value measured at 1V differential.

**Characteristics Curve**

**Fig 1. Dropout Characteristics**

**Fig 2. Input Current**

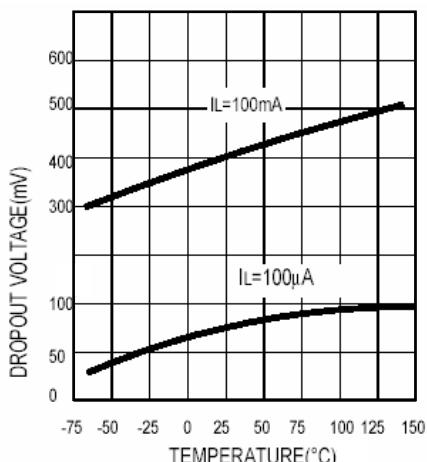


Fig 3. Dropout Voltage

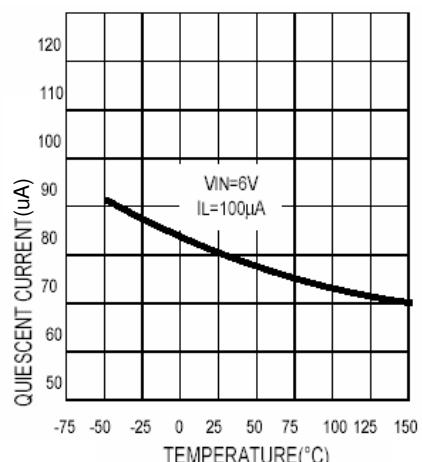


Fig 4. Ground Pin Current

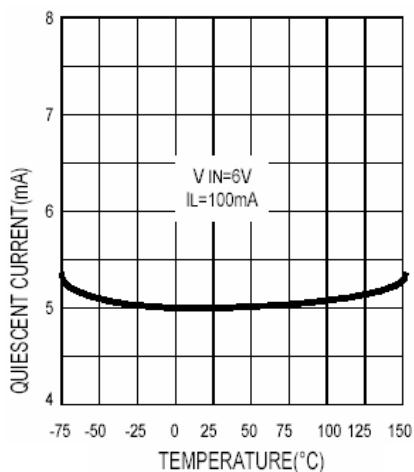


Fig 5. Ground Pin Current

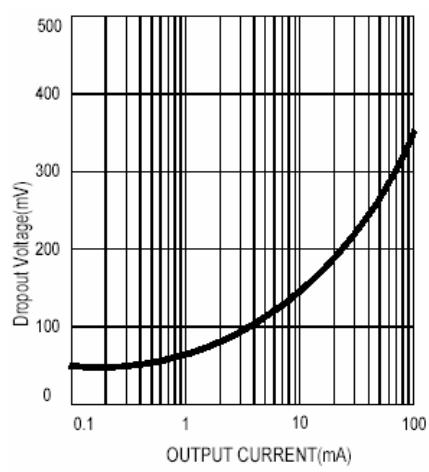


Fig 6. Dropout Voltage

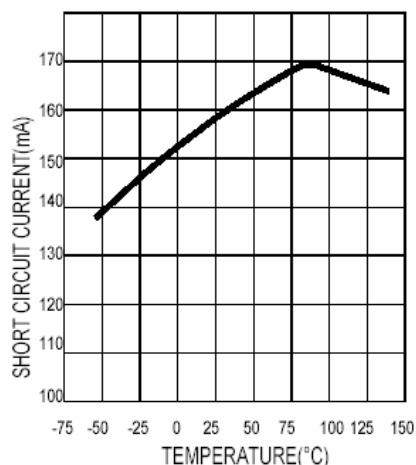


Fig 7. Short Circuit Current

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